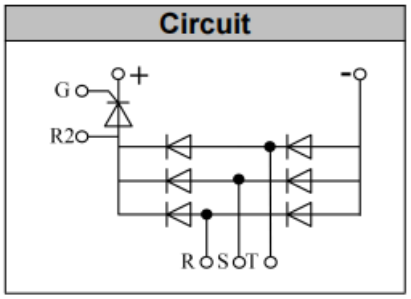


Three Phase Bridge &Thyristor Module

VRRM / VDRM 800 to 1800V
ID 200 A



Applications

- Inverter for AC or DC motor control
- Current stablilzed power supply
- Switching power supply

Features

- High Surge Capability
- Glass passivated chip
- Simple Mounting
- Heat transfer through aluminum oxide DBC ceramic isolated metal baseplate

Module Type

TYPE	VRRM/VDRM	VRSM
MT200DT08L2 MT200DT12L2 MT200DT16L2 MT200DT18L2	800V 1200V 1600V 1800V	900V 1300V 1700V 1900V

□Diode

Maximum Ratings

Symbol	Conditions	Values	Units
I_D	Three phase, full wave Tc=90□	200	A
I_{FSM}	t=10ms T_J=25□	2240	A
I^2t	t=10ms T_J=25□	25000	A^2s
V_{ISO}	AC 50Hz/60Hz; R.M.S; 1min	3000	V
T_J		-40 to +150	□
Tstg		-40 to +125	□
Mt	To Terminals(M4)	2±15%	N·m
	To Terminals(M6)	5±15%	
Ms	To Heatsink(M6)	5±15%	
Weight		310	g

Thermal Characteristics

Symbol	Conditions	Values	Units
Rth(j-c)	Junction to Case(Per Module)	0.15	□/W
Rth(c-s)	Case to Heat Sink	0.05	□/W

Electrical Characteristics

Symbol	Conditions	Values			Units
		Min.	Typ.	Max.	
V_{FM}	T_J=25□ I_F =200A	—	—	1.35	V
I_{RD}	T_J=150□ V_R=V_{RRM}	—	—	5	mA
r_F	T_J=125□		2.3		mΩ
VF0			0.8		V

□Thyristor
Maximum Ratings

Symbol	Conditions	Values	Units
I_{TAV}	Single phase ,half wave 180°conduction Tc=90□	200	A
I_{TSM}	t=10ms T_J=25□	4500	A
I^2t	t=10ms T_J=25□	101200	A^2s
V_{ISO}	AC 50Hz/60Hz; R.M.S; 1min	3000	V
T_J		-40 to +125	□
Tstg		-40 to +125	□
di/dt	Tj =125□, 2/3VDRM ,IG =500mA Tr<0.5us,tp>6us	200	A/us
a	Maximum allowable acceleration	50	m/s^2

Thermal Characteristics

Symbol	Conditions	Values	Units
Rth(j-c)	Junction to Case(Per Thyristor)	0.15	□/W
Rth(c-s)	Case to Heat Sink	0.05	□/W

Electrical Characteristics

Symbol	Conditions	Values			Units
		Min.	Typ.	Max.	
V_{TM}	T_J =25□ IT=200A			1.35	V
I_{RRM}/I_{DRM}	T_J =25□ ,V_R=V_{RRM} ,V_D=V_{DRM}			30	mA
V_{T0}	T_J=25□			0.85	V
rT	T_J=25□			1.2	mΩ
V_{GT}	T_J=25□, V_D =6V			3	V
I_{GT}	T_J=25□, V_D =6V			200	mA
V_{GD}	T_J=125□, V_D =2/3V_{DRM}			0.25	V
I_{GD}	T_J=125□, V_D =2/3V_{DRM}			10	mA
I_L	T_J=25□, R_G = 33 Ω			300	mA
I_H	T_J=25□, V_D=6V			200	mA
t_{gd}	T_J =25□, I_G=1A, diG/dt=1A/us		1		us
t_q	T_J=125□		100		us
dv/dt	T_{jj} =125□,2/3V_{DRM}, linear voltage rise		1000		V/us

Performance Curves

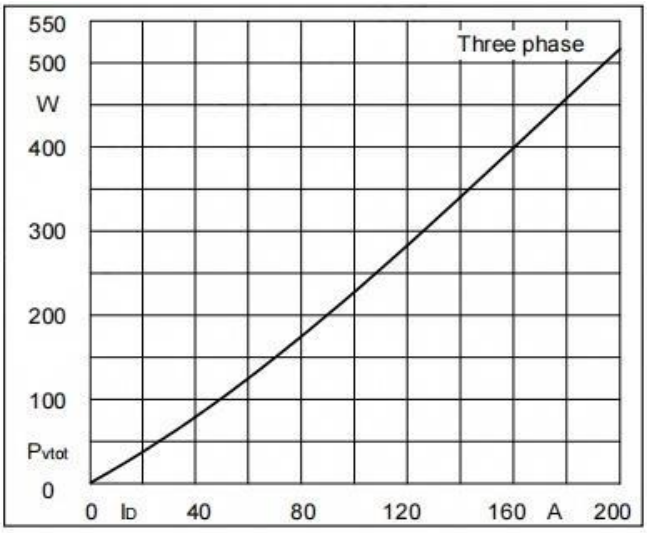


Fig1. Power dissipation

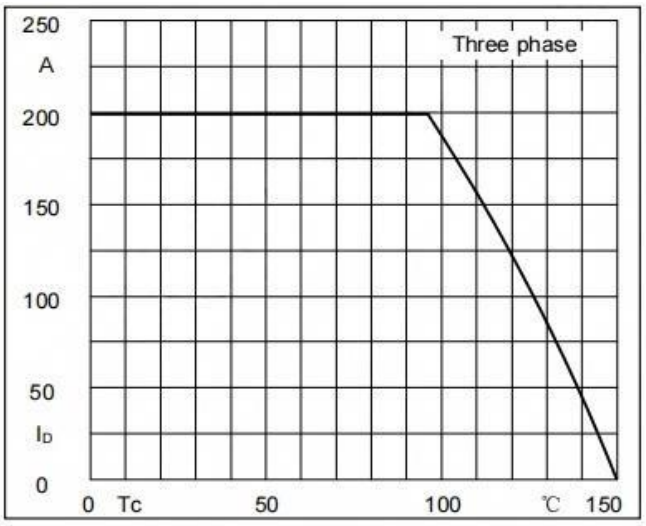


Fig2.Forward Current Derating Curve

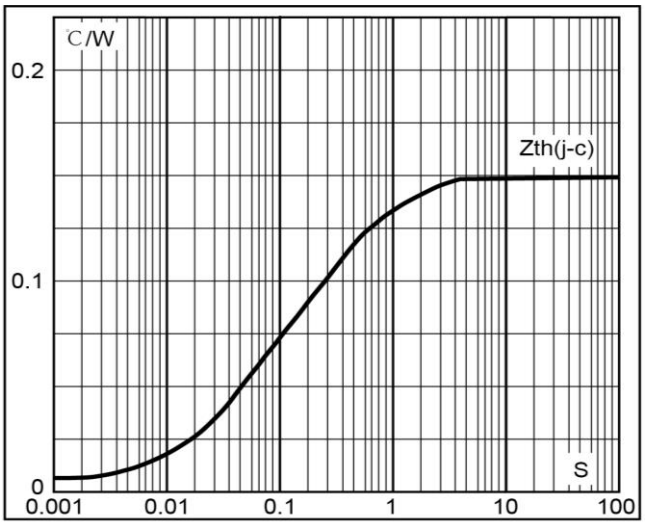


Fig3. Transient thermal impedance

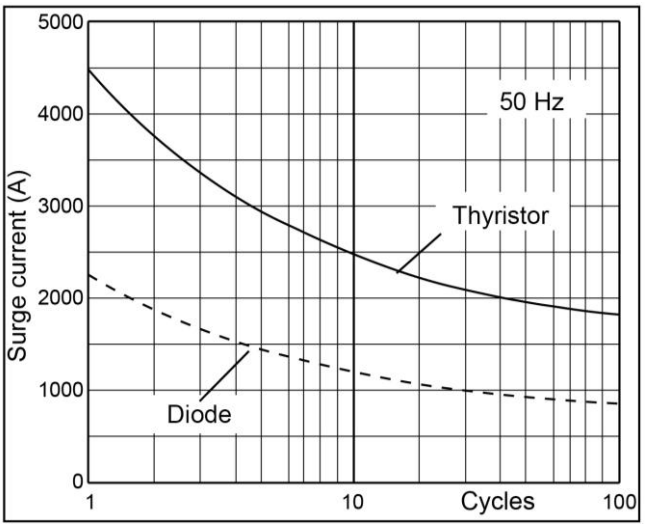


Fig4. Max Non-Repetitive Forward Surge Current

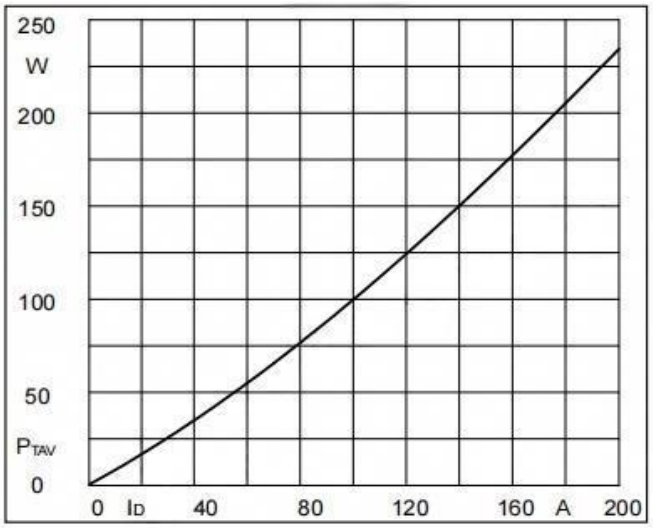


Fig5. SCR Power dissipation

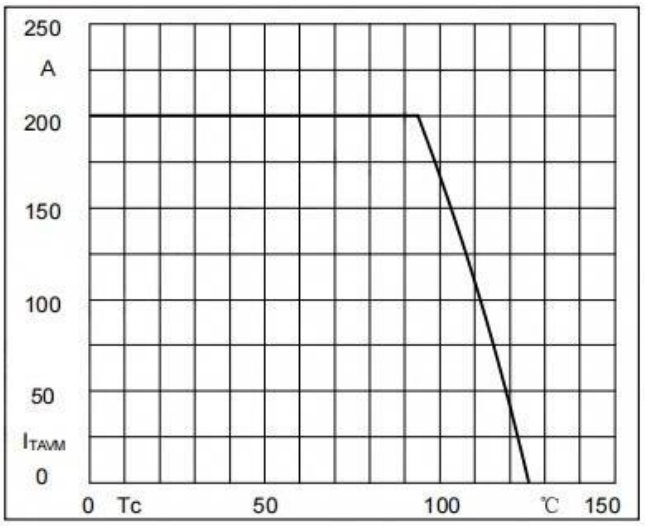


Fig6. SCR Forward Current Derating Curve

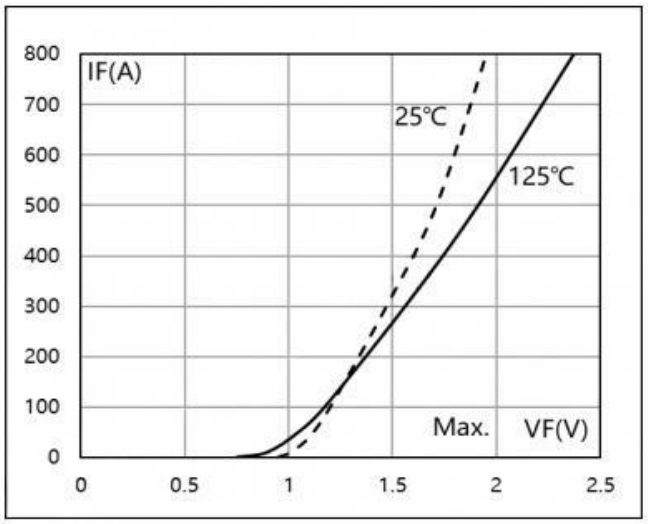


Fig7. Forward Characteristics

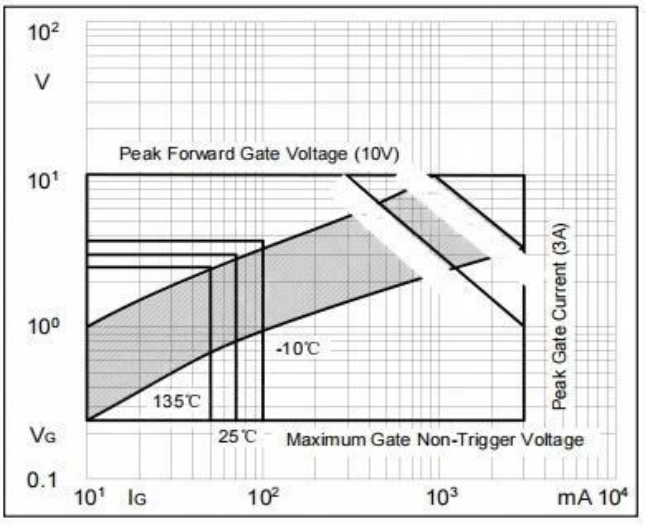
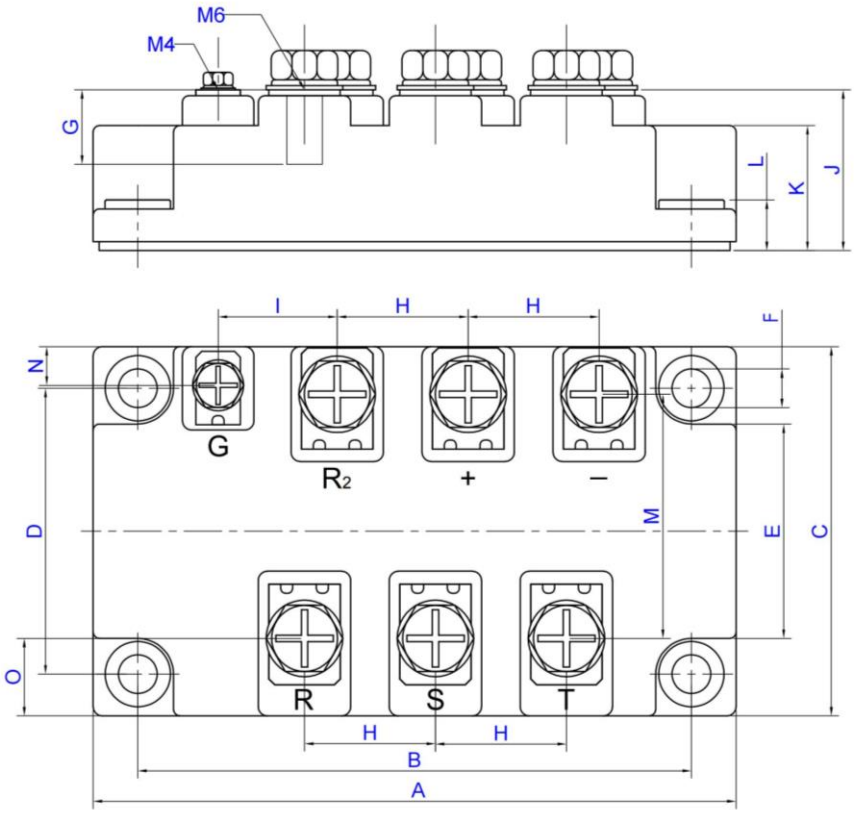


Fig8. Gate trigger Characteristics

Package Outline Information

CASE: L2



DIM	Min (mm)	Max (mm)	Note
A	108	109	
B	92.5	93.5	
C	61.5	62.5	
D	47.5	48.5	
E	35.5	36.5	
F	6.2	6.8	Ø
G	12	13	
H	21.5	22.5	
I	19.5	20.5	
J	26.5	27.5	
K	20.5	21.5	
L	8	9	
M	40.5	41.5	
N	6	7	
O	12.5	13.5	

Packing Standard

Item	Length: A(mm)	Width: B(mm)	Height: C (mm)	Quantity (PCS)
Inner Box	276	258	48	4
Outer Carton	545	295	240	40

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